XC6126 Series

ETR0214-004

Ultra Small, Highly Accurate, Single Voltage Detector

■GENERAL DESCRIPTION

The XC6126 series is an ultra small, highly accurate CMOS single voltage detector with very low power consumption. The device includes a highly accurate reference voltage source and uses laser trimming technologies, it maintains high accuracy over the full operation temperature range.

The device is available in both CMOS and N-channel open drain output configurations.

Ultra small package USPN-4B02 is ideally suited for small design of portable devices and high densely mounting applications. The conventional package SSOT-24 is also available for upper compatible replacements.

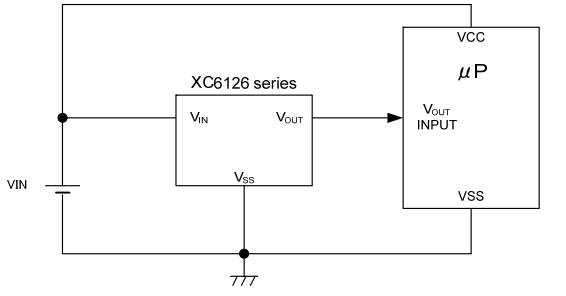
■APPLICATIONS

- Microprocessor logic reset circuitry
- System battery life and charge voltage monitors
- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection

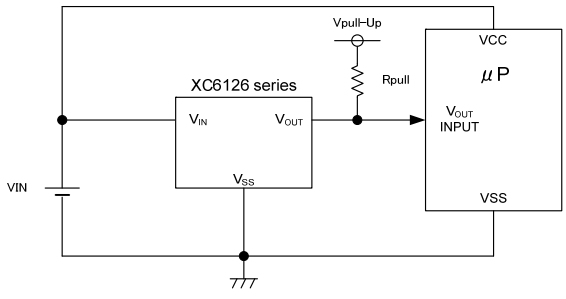
■FEATURES

High Accuracy	:	±0.8% (25℃)
Temperature Characteristics	:	±50ppm /℃ (TYP.)
Low Power Consumption	:	0.6μA (TYP.) (Detect: V_{DF}=1.8V, V_{IN}=1.62V) 0.7μA (TYP.) (Release: V_{DF}=1.8V, V_{IN}=1.98V)
Operating Voltage Range	:	0.7V～6.0V
Detect Voltage Range	:	1.5V～5.5V (0.1V increments)
Output Configuration	:	N-channel open drain output CMOS output
Detect Logic	:	Active Low Reset
Packages	:	USPN-4B02, SSOT-24
Environmentally Friendly	:	EU RoHS Compliant, Pb Free

■TYPICAL APPLICATION CIRCUIT



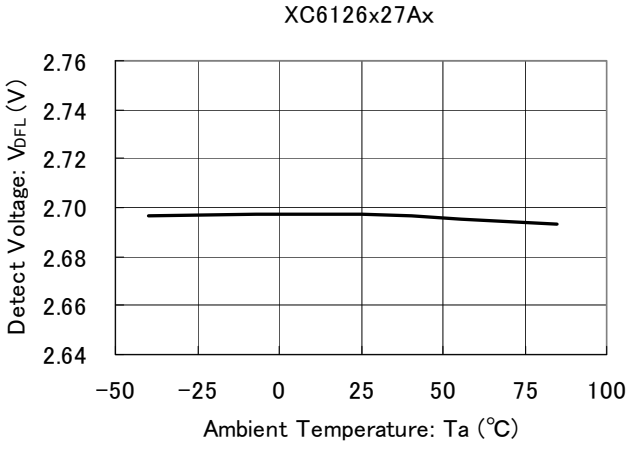
CMOS output



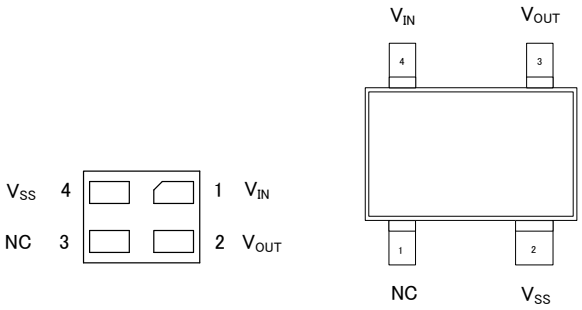
N-ch open drain output

■ TYPICAL PERFORMANCE CHARACTERISTICS

●Detect Voltage vs. Ambient Temperature



■PIN CONFIGURATION



USPN-4B02
(BOTTOM VIEW)

SSOT-24
(TOP VIEW)

■PIN ASSIGNMENT

PIN NUMBER		PIN NAME	FUNCTIONS
USPN-4B02	SSOT-24		
1	4	V_{IN}	Power Input
2	3	V_{OUT}	Signal Output (Active Low)
3	1	NC	No connection
4	2	V_{SS}	Ground

■PRODUCT CLASSIFICATION

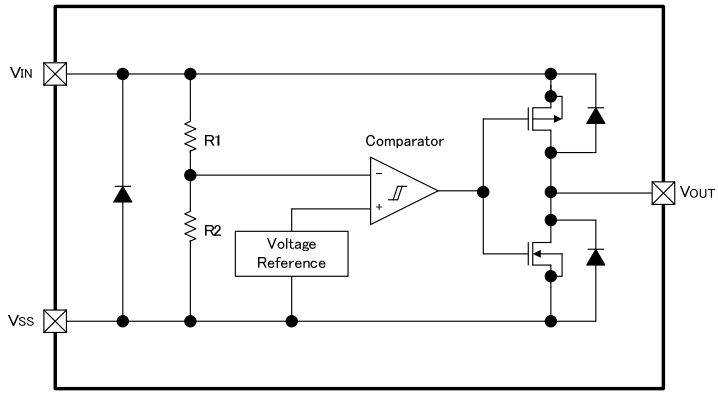
●Ordering Information

XC6126①②③④⑤⑥-⑦(*1)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Output Configuration	C	CMOS Output
		N	N-ch Open Drain Output
②③	Detect Voltage	15~55	e.g. 2.7V → ②=2, ③=7
④	Detect Accuracy	A	±0.8%
⑤⑥-⑦(*1)	Packages (Order Unit)	7R-G	USPN-4B02 (5,000/Reel)
		NR-G	SSOT-24 (3,000/Reel)

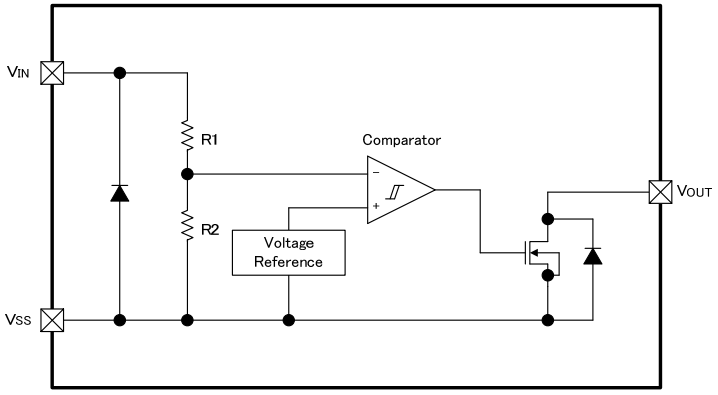
(*1) The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

■BLOCK DIAGRAMS



XC6126C Series

* Diodes inside the circuits are ESD protection diodes and parasitic diodes.



XC6126N Series

* Diodes inside the circuits are ESD protection diodes.

■ABSOLUTE MAXIMUM RATINGS

Ta=25℃

PARAMETER		SYMBOL	RATING	UNITS
Input Voltage		V_{IN}	V_{SS}-0.3～+6.5	V
Output Current		I_{OUT}	20	mA
Output Voltage	XC6126C (*1)	V_{OUT}	V_{SS}-0.3～V_{IN}+0.3≦6.5	V
	XC6126N (*2)		V_{SS}-0.3～+6.5	
Power Dissipation	USPN-4B02	Pd	100	mW
	SSOT-24		150	
Operating Temperature Range		Topr	-40～+85	°C
Storage Temperature Range		Tstg	-55～+125	°C

Note:
(*1) CMOS Output
(*2) N-ch Open Drain Output

■ELECTRICAL CHARACTERISTICS

XC6126 Series

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Operating Voltage	V_{IN}	$V_{DF(T)}$(*1)=1.5～5.5V(*2)	0.7 (*3)		6.0	V	-
Detect Voltage	V_{DFL}	$V_{DF(T)}$=1.5～5.5V	$V_{DF(T)}$ ×0.992	$V_{DF(T)}$	$V_{DF(T)}$ ×1.008	V	①
			E-1 (*4)				
Hysteresis Width	V_{HYS}		V_{DFL} ×0.02	V_{DFL} ×0.05	V_{DFL} ×0.08	V	①
Supply Current 1	I_{SS1}	V_{IN}=V_{DFL}×0.9				μA	②
		$V_{DF(T)}$=1.5～1.8V	-	0.6	1.3		
		$V_{DF(T)}$=1.9～3.0V	-	0.7	1.5		
		$V_{DF(T)}$=3.1～5.5V	-	0.9	1.85		
Supply Current 2	I_{SS2}	V_{IN}=V_{DFL}×1.1(*5)				μA	②
		$V_{DF(T)}$=1.5～1.8V	-	0.7	1.55		
		$V_{DF(T)}$=1.9～3.0V	-	0.8	1.75		
		$V_{DF(T)}$=3.1～5.5V	-	1.0	2.25		
Output Current	I_{OUT1}	V_{IN}=0.7V,V_{OUT}=0.5V(N-ch)	0.008	0.2	-	mA	③
		V_{IN}=1.0V, V_{OUT}=0.5V(N-ch)	0.6	1.5	-		
		V_{IN}=2.0V(*6), V_{OUT}=0.5V(N-ch)	4.5	7.0	-		
		V_{IN}=3.0V(*7),V_{OUT}=0.5V(N-ch)	7.0	10.0	-		
		V_{IN}=4.0V(*8),V_{OUT}=0.5V(N-ch)	8.5	11.5	-		
		V_{IN}=5.0V(*9),V_{OUT}=0.5V(N-ch)	9.5	13.0	-		
	I_{OUT2} (*10)	V_{IN}=6.0V,V_{OUT}=5.5V(P-ch)	-	-4.6	-2.8	mA	③
Leakage Current CMOS Output	I_{LEAK}	V_{IN}=V_{DFL}×0.9,V_{OUT}=0V	-	-0.01	-	μA	③
Leakage Current N-ch Open Drain Output		V_{IN}=6.0V,V_{OUT}=6.0V	-	0.01	0.15	μA	
Temperature Characteristics	ΔV_{DFL}/ (ΔTopr･V_{DFL})	-40℃≦Topr≦85℃	-	±50	-	ppm/℃	①
Detect Delay Time(*11)	t_{DF}	V_{IN}=V_{DFL}×1.1(*5)→V_{DFL}×0.9	-	30	100	μs	④
Release Delay Time(*12)	t_{DR}	V_{IN}=V_{DFL}×0.9→V_{DFL}×1.1(*5)	-	20	50	μs	④

Note:
(*1) $V_{DF(T)}$: Nominal detect voltage
(*2) For the N-ch Open Drain, Rpull=1MΩ, Vpull-Up=V_{IN}.
Rpull：An External Pull-up resistor
Vpull-Up：Pull-up Voltage
(*3)V_{IN} voltage for V_{OUT}≦0.3V is under detect state.
(*4)For the detail value, please refer to “Voltage Table” in next page.
(*5) V_{IN}=6.0V where $V_{DF(T)}$= 5.5V.
(*6) For $V_{DF(T)}$＞2.0V products.
(*7) For $V_{DF(T)}$＞3.0V products.
(*8) For $V_{DF(T)}$＞4.0V products.
(*9) For $V_{DF(T)}$＞5.0V products.
(*10)For the XC6126C (CMOS output)
(*11) A time between V_{IN}=V_{DFL} and V_{OUT}=V_{DFL}×0.45 when V_{IN} falls.
(*12) A time between V_{IN}=V_{DFL}+V_{HYS} and V_{OUT}=V_{DFL}×0.55 when V_{IN} rises.

■ELECTRICAL CHARACTERISTICS (Continued)

Voltage Table 1

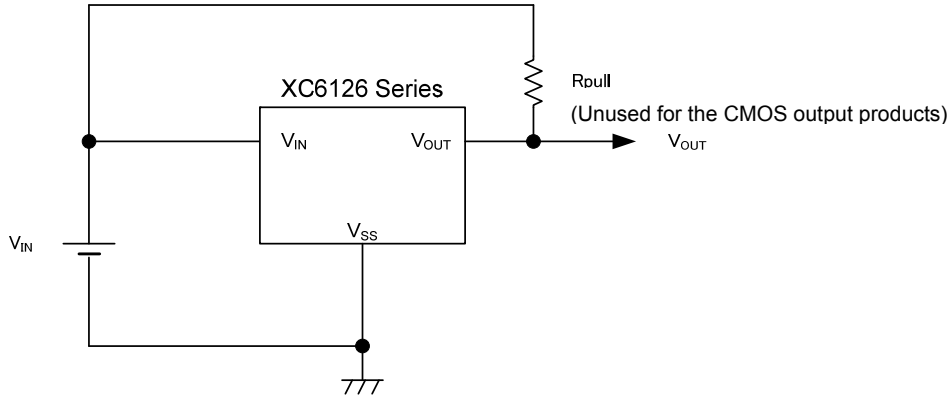
NOMINAL DETECT VOLTAGE (V)	DETECT VOLTAGE (V) E-1	
$V_{DF(T)}$	V_{DFL}	
	MIN.	MAX.
1.50	1.4880	1.5120
1.60	1.5872	1.6128
1.70	1.6864	1.7136
1.80	1.7856	1.8144
1.90	1.8848	1.9152
2.00	1.9840	2.0160
2.10	2.0832	2.1168
2.20	2.1824	2.2176
2.30	2.2816	2.3184
2.40	2.3808	2.4192
2.50	2.4800	2.5200
2.60	2.5792	2.6208
2.70	2.6784	2.7216
2.80	2.7776	2.8224
2.90	2.8768	2.9232
3.00	2.9760	3.0240
3.10	3.0752	3.1248
3.20	3.1744	3.2256
3.30	3.2736	3.3264
3.40	3.3728	3.4272
3.50	3.4720	3.5280
3.60	3.5712	3.6288
3.70	3.6704	3.7296
3.80	3.7696	3.8304
3.90	3.8688	3.9312
4.00	3.9680	4.0320

Voltage Table 2

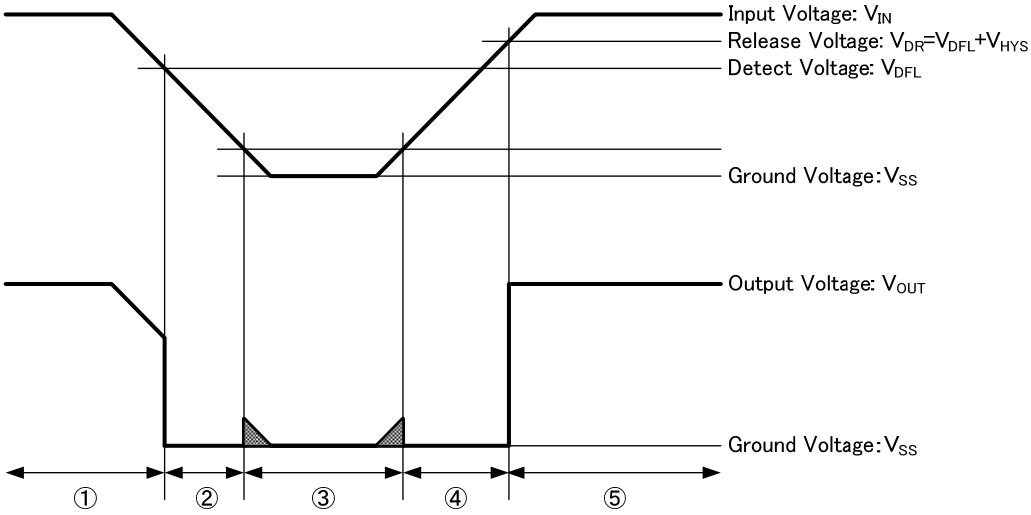
NOMINAL DETECT VOLTAGE (V)	DETECT VOLTAGE (V) E-1	
$V_{DF(T)}$	V_{DFL}	
	MIN.	MAX.
4.10	4.0672	4.1328
4.20	4.1664	4.2336
4.30	4.2656	4.3344
4.40	4.3648	4.4352
4.50	4.4640	4.5360
4.60	4.5632	4.6368
4.70	4.6624	4.7376
4.80	4.7616	4.8384
4.90	4.8608	4.9392
5.00	4.9600	5.0400
5.10	5.0592	5.1408
5.20	5.1584	5.2416
5.30	5.2576	5.3424
5.40	5.3568	5.4432
5.50	5.4560	5.5440

■OPERATIONAL EXPLANATION

●Typical Application Circuit



●Timing Chart



The above uses a timing chart to explain the operation of the circuit indicated in the operation explanation circuit schematic.

(1) In the initial state, an input voltage (V_{IN}) higher than the release voltage (V_{DR}) is applied, and V_{IN} gradually drops.
When a voltage higher than the detect voltage (V_{DFL}) is applied to the input voltage (V_{IN}), the output voltage (V_{OUT}) is equal to the input voltage (V_{IN}).
*On the N-ch open drain output product, the VOUT pin is in a high impedance state, and when the output is pulled up, the output voltage (V_{OUT}) is equal to the pull-up voltage.

(2) When the input voltage (V_{IN}) drops below the detect voltage (V_{DFL}), the output voltage (V_{OUT}) is equal to the ground voltage (V_{SS}). (Detection state)
*This also applies to the N-ch open drain output product.

(3) If the input voltage (V_{IN}) drops below the minimum operating voltage (0.7V), the output becomes unstable.
*If the output pin on the N-ch open drain output product is pulled up, the pull-up voltage may be output as the output voltage (V_{OUT}).

(4) The output voltage (V_{OUT}) remains at the ground voltage as the input voltage (V_{IN}) rises past the minimum operating voltage (0.7V) and reaches the release voltage (V_{DR}).

(5) If the input voltage (V_{IN}) rises higher than the release voltage (V_{DR}), the output voltage (V_{OUT}) is equal to the input voltage (V_{IN}).
*On the N-ch open drain output product, the VOUT pin is in a high impedance state, and if the output is pulled up, the pull-up voltage is output as the output voltage (V_{OUT}) as in (1).

(6) The difference between the release voltage (V_{DR}) and the detect voltage (V_{DFL}) is the hysteresis width (V_{HYS}).

Note: For simplicity, the above explanation omits the circuit operation time.

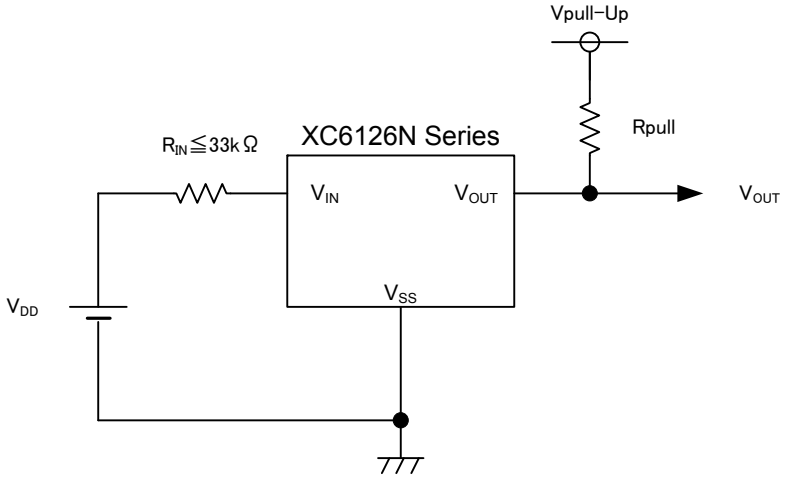
■NOTE ON USE

1. Please use this IC within the stated maximum ratings. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.

2. Note that there is a possibility of malfunctioning if the input voltage changes sharply or undergoes repeated, cyclical changes.

3. If the resistance R_{IN} is connected between the V_{IN} pin and the power supply V_{DD}, the voltage drop due to the flow through current in the internal circuit and R_{IN} may cause oscillation when release takes place. When using the CMOS output product, oscillation due to R_{IN} and the flow through current may occur without relation to release and detection, and thus R_{IN} should not be connected.

4. Please use N-ch open drains configuration, when a resistor R_{IN} is connected between the V_{IN} pin and the power supply V_{DD}. In such cases, please ensure that R_{IN} is less than 33kΩ.



[Figure 1: Circuit connected with the input resistor fro N-ch open drain]

5. When N-ch open drain output is used, the V_{OUT} voltage at detection is determined by the pull-up resistance connected to the output pin. Select the resistance based on the following considerations:

At detection: V_{OUT} = (Vpull-Up)/(1+Rpull/R_{ON})
Vpull-Up: Voltage after pull-up
R_{ON}(*1): ON resistance of N-ch driver (calculated from V_{OUT}/I_{OUT1} based on electrical characteristics) (*3)

Example:
When V_{IN} = 2.0V (*2), R_{ON} = 0.5/4.5 × 10-3≒111Ω （MAX.）. If it is desired to make the V_{OUT} voltage at detection 0.1V or less when Vpull-Up is 3.0 V,
Rpull = (Vpull-Up /V_{OUT-1}) × R_{ON}=(3/0.1-1) × 111 ≒ 3.2kΩ
Therefore, to make the output voltage at detection 0.1 V or less under the above conditions, the pull-up resistance must be 3.2kΩ or higher.

(*1) Note that R_{ON} becomes larger as V_{IN} becomes smaller.
(*2) For V_{IN} in the calculation, use the lowest value of the input voltage range you will use.
(*3) I_{OUT1} in the electrical characteristics is at Ta = 25℃. I_{OUT1} varies depending on the ambient temperature.
To select a pull-up resistance taking ambient temperature into account, consult us.

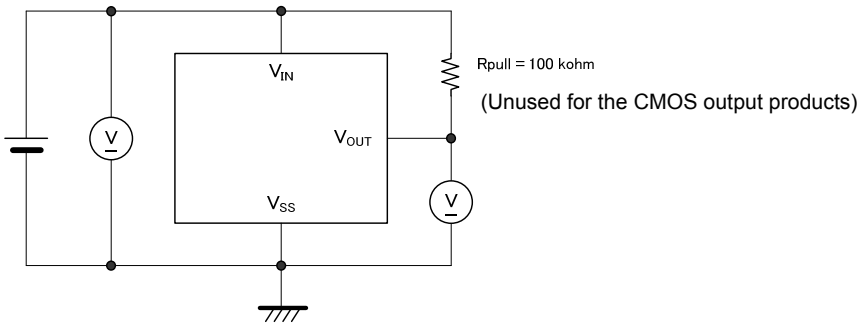
At release: V_{OUT} = (Vpull-Up)/(1+Rpull/R_{OFF})
Vpull-Up: Voltage after pull-up
R_{OFF}: 40MΩ (MIN.) resistance when N-ch driver is OFF (calculated from V_{OUT}/I_{LEAK} based on electrical characteristics)

Example:
Making V_{OUT} 5.99 V or higher when Vpull-Up is 6.0 V:
Rpull = (Vpull-Up/V_{OUT-1}) × R_{OFF} = (6/5.99-1) × 40 × 106 ≒ 66 kΩ
Therefore, to make the output voltage at release 5.99 V or higher under the above conditions, the pull-up resistance must be 66kΩ or less.

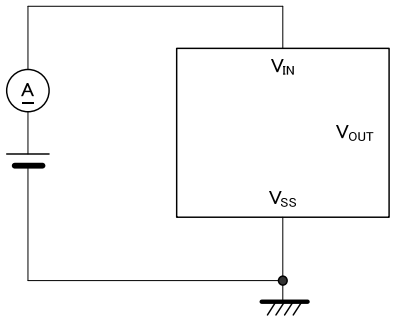
6. Torex places an importance on improving our products and its reliability.
However, by any possibility, we would request user fail-safe design and post-aging treatment on system or equipment.

■TEST CIRCUITS

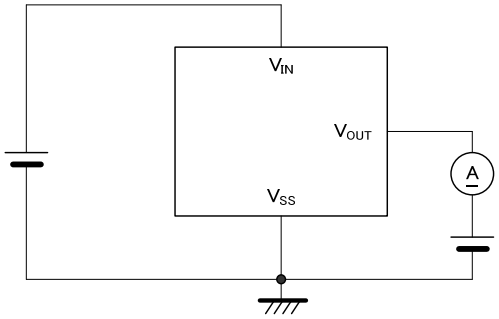
Circuit 1



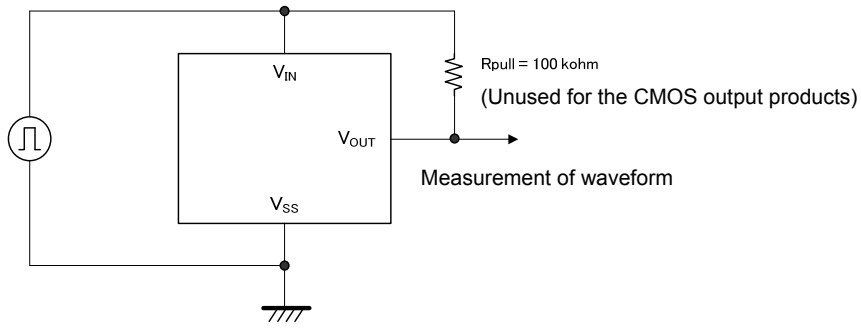
Circuit 2



Circuit 3

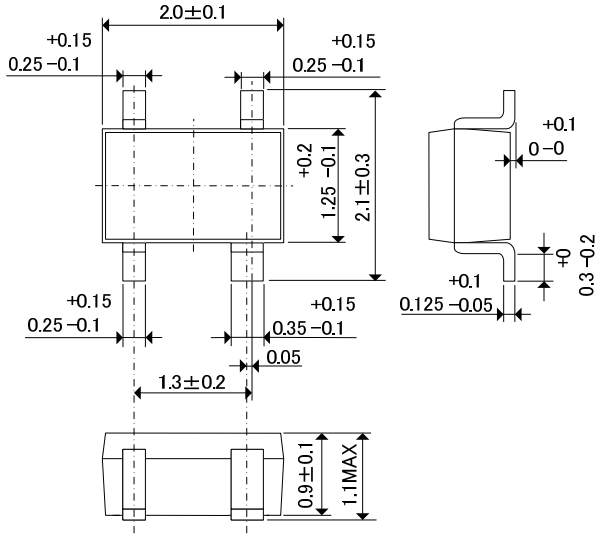


Circuit 4

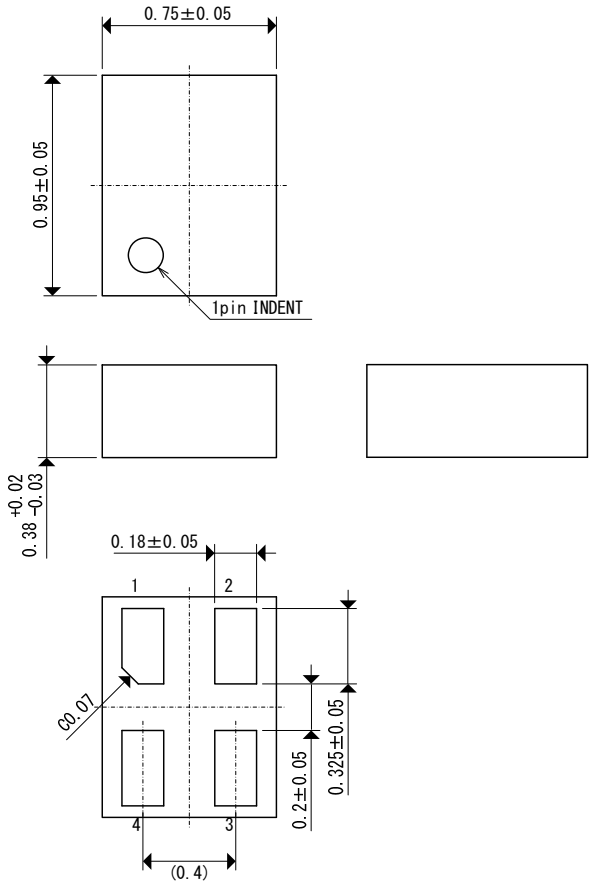


■PACKAGING INFORMATION

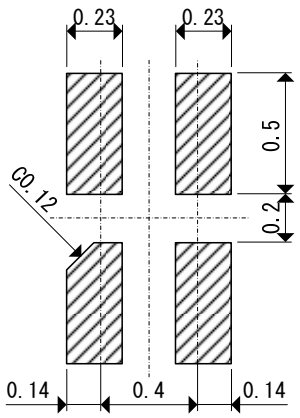
●SSOT−24 (unit：mm)



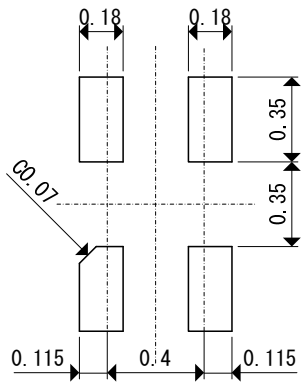
●USPN−4B02 (unit：mm)



●USPN-4B02 Reference Pattern Layout (unit : mm)

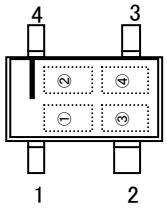


●USPN-4B02 Reference Metal Mask Design (unit : mm)



■MARKING RULE

SSOT-24 (With the orientation bar at the top)



① represents product series, detect voltage range and output configuration.

MARK	OUTPUT CONFIGURATION	DETECT VOLTAGE RANGE[V]	PRODUCT SERIES
1	CMOS	1.5～2.5	XC6126C15A**-G ～ XC6126C25A**-G
2	CMOS	2.6～5.5	XC6126C26A**-G ～ XC6126C55A**-G
3	Nch	1.5～2.5	XC6126N15A**-G ～ XC6126N25A**-G
4	Nch	2.6～5.5	XC6126N26A**-G ～ XC6126N55A**-G

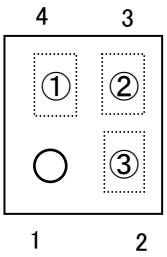
② represents detect voltage.

MARK	DETECT VOLTAGE (V)		MARK	DETECT VOLTAGE (V)		MARK	DETECT VOLTAGE (V)	
0	-	2.6	A	-	3.6	N	1.6	4.6
1	-	2.7	B	-	3.7	P	1.7	4.7
2	-	2.8	C	-	3.8	R	1.8	4.8
3	-	2.9	D	-	3.9	S	1.9	4.9
4	-	3.0	E	-	4.0	T	2.0	5.0
5	-	3.1	F	-	4.1	U	2.1	5.1
6	-	3.2	H	-	4.2	V	2.2	5.2
7	-	3.3	K	-	4.3	X	2.3	5.3
8	-	3.4	L	-	4.4	Y	2.4	5.4
9	-	3.5	M	1.5	4.5	Z	2.5	5.5

③④ represents production lot number
01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to AZ, B1 to ZZ repeated
(G, I, J, O, Q, W excluded)
*No character inversion used.

■MARKING RULE (Continued)

USPN-4B02



① represents product series, detect voltage range and output configuration.

MARK	OUTPUT CONFIGURATION	DETECT VOLTAGE RANGE[V]	PRODUCT SERIES
4	CMOS	1.5～2.5	XC6126C15A**-G ～ XC6126C25A**-G
5	CMOS	2.6～5.5	XC6126C26A**-G ～ XC6126C55A**-G
6	Nch	1.5～2.5	XC6126N15A**-G ～ XC6126N25A**-G
7	Nch	2.6～5.5	XC6126N26A**-G ～ XC6126N55A**-G

② represents detect voltage.

MARK	DETECT VOLTAGE (V)		MARK	DETECT VOLTAGE (V)		MARK	DETECT VOLTAGE (V)	
0	-	2.6	A	-	3.6	N	1.6	4.6
1	-	2.7	B	-	3.7	P	1.7	4.7
2	-	2.8	C	-	3.8	R	1.8	4.8
3	-	2.9	D	-	3.9	S	1.9	4.9
4	-	3.0	E	-	4.0	T	2.0	5.0
5	-	3.1	F	-	4.1	U	2.1	5.1
6	-	3.2	H	-	4.2	V	2.2	5.2
7	-	3.3	K	-	4.3	X	2.3	5.3
8	-	3.4	L	-	4.4	Y	2.4	5.4
9	-	3.5	M	1.5	4.5	Z	2.5	5.5

③ represents production lot number
0 to 9, A to Z repeated. (G, I, J, O, Q, W excluded)
*No character inversion used.

1. The products and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this datasheet is up to date.
2. We assume no responsibility for any infringement of patents, patent rights, or other rights arising from the use of any information and circuitry in this datasheet.
3. Please ensure suitable shipping controls (including fail-safe designs and aging protection) are in force for equipment employing products listed in this datasheet.
4. The products in this datasheet are not developed, designed, or approved for use with such equipment whose failure of malfunction can be reasonably expected to directly endanger the life of, or cause significant injury to, the user.
   (e.g. Atomic energy; aerospace; transport; combustion and associated safety equipment thereof.)
5. Please use the products listed in this datasheet within the specified ranges.
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6. We assume no responsibility for damage or loss due to abnormal use.
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